## 捷多邦,专业PCB打样工厂,24小时加急出货

Philips Semiconductors

### Rectifier diodes fast, soft-recovery

**Product specification** 

#### **BY329X series**

MAX.

-1200

1200

8

65

145

UNIT

V

А

А

ns

#### GENERAL DESCRIPTION

Glass-passivated double diffused rectifier diodes in a full pack plastic envelope featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

DESCRIPTION

#### PINNING - SOD113

cathode

anode

isolated

PIN

1 2

case

# PIN CONFIGURATION

2

QUICK REFERENCE DATA

voltage

PARAMETER

Repetitive peak reverse

Average forward current

Reverse recovery time

Non-repetitive peak

forward current

SYMBOL

V<sub>RRM</sub>

F(AV)

FSM

t<sub>rr</sub>

#### SYMBOL

MAX.

-800

800

8

65

145

**BY329X** 

MAX.

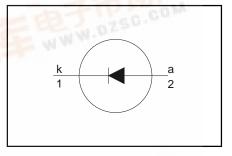
-1000

1000

8

65

145



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
V <sub>RSM</sub>	Non-repetitive peak reverse voltage	5 60 1B	122	<b>-800</b> 800	<b>-1000</b> 1000	<b>-1200</b> 1200	V
V <sub>RRM</sub> V <sub>RWM</sub>	Repetitive peak reverse voltage Crest working reverse voltage	COM	-	800 600	1000 800	1200 1000	V V
I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave; δ = 0.5; T <sub>hs</sub> ≤ 83 °C	-		8		A
-182		sinusoidal; a = 1.57; T <sub>hs</sub> ≤ 90 °C	-		7		A
I <sub>F(RMS)</sub>	RMS forward current	115	-		11		Α
I <sub>FRM</sub>	Repetitive peak forward current	t = 25 μs; δ = 0.5; T <sub>hs</sub> ≤ 83 °C	-	da-	16		A
I <sub>FSM</sub>	Non-repetitive peak forward current.	t = 10 ms t = 8.3 ms sinusoidal; $T_i = 150$ °C prior to surge; with reapplied	127	WW	65 71		A A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	V <sub>RWM(max)</sub> t = 10 ms	-		28		A <sup>2</sup> s
T <sub>stg</sub>	Storage temperature		-40		150		°C
T	Operating junction temperature		-		150		°C

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#### **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. $\leq$ 65% ; clean and dustfree	-		2500	V
C <sub>isol</sub>	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub> R <sub>th j-a</sub>	Thermal resistance junction to heatsink Thermal resistance junction to ambient	with heatsink compound without heatsink compound in free air.		- - 55	4.8 5.9 -	K/W K/W K/W

#### STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

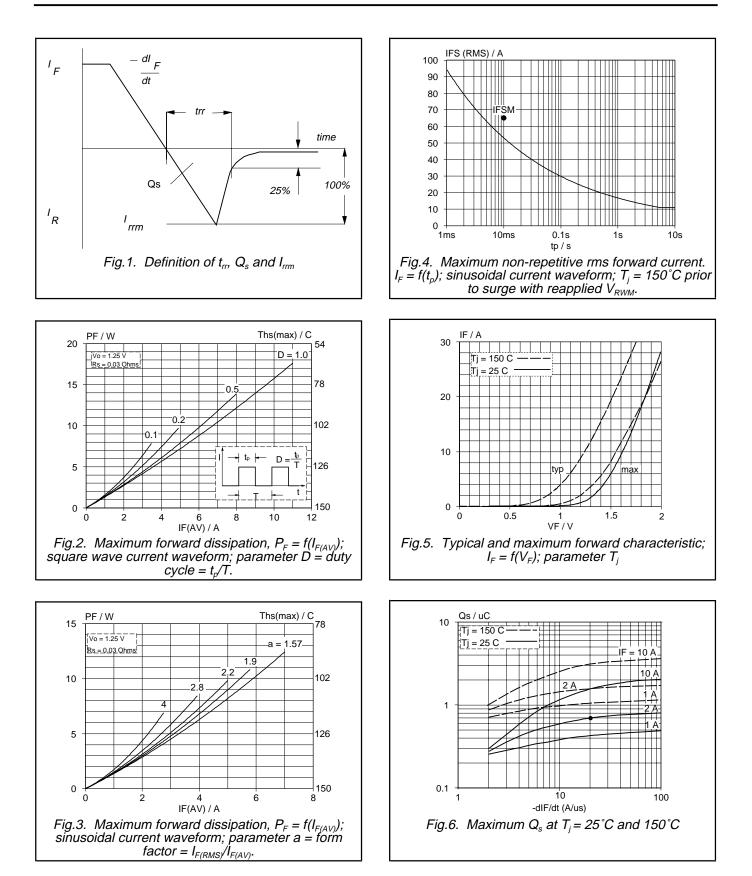
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 20 A	-	1.5	1.85	V
I <sub>R</sub>	Reverse current	V <sub>R</sub> = V <sub>RWM</sub> ; T <sub>j</sub> = 125 °C	-	0.1	1.0	mA

#### **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t <sub>rr</sub> Q <sub>s</sub> dI <sub>R</sub> /dt	Reverse recovery charge	$ \begin{array}{l} I_{\text{F}} = 1 \; \text{A}; \; V_{\text{R}} \geq 30 \; \text{V}; \; \text{-dI}_{\text{F}}/\text{dt} = 50 \; \text{A}/\mu\text{s} \\ I_{\text{F}} = 2 \; \text{A}; \; V_{\text{R}} \geq 30 \; \text{V}; \; \text{-dI}_{\text{F}}/\text{dt} = 20 \; \text{A}/\mu\text{s} \\ I_{\text{F}} = 2 \; \text{A}; \; \text{-dI}_{\text{F}}/\text{dt} = 20 \; \text{A}/\mu\text{s} \end{array} $		125 0.5 50	145 0.7 60	ns μC A/μs

## Rectifier diodes fast, soft-recovery

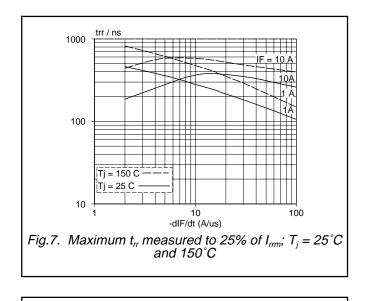


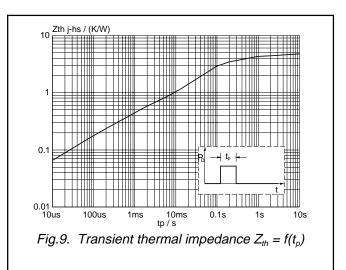
#### BY329X series

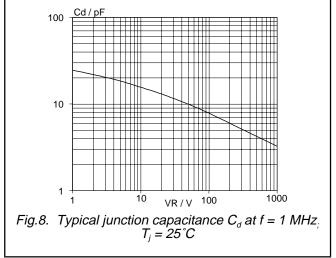
Product specification

# Rectifier diodes fast, soft-recovery

#### BY329X series



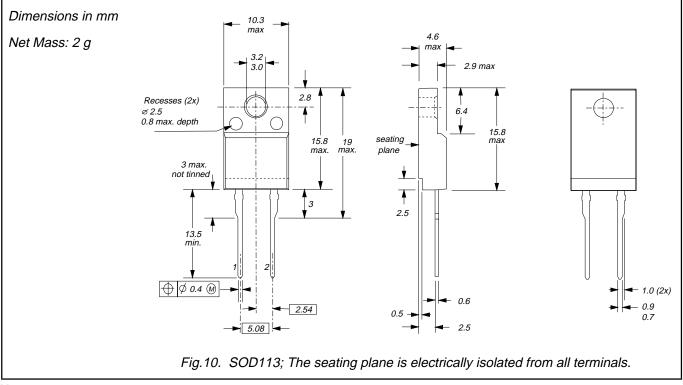




#### **Rectifier diodes** fast, soft-recovery

#### **BY329X** series

#### **MECHANICAL DATA**



Notes

Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

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#### BY329X series

#### DEFINITIONS

Data sheet status						
Objective specification	This data sheet contains target or goal specifications for product development.					
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.					
Product specification	This data sheet contains final product specifications.					

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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